## SF1001G – SF1008G

Taiwan Semiconductor

# 10A, 50V - 600V Super Fast Rectifier

## **FEATURES**

- AEC-Q101 qualified available
- High efficiency, low V<sub>F</sub>
- High current capability
- High surge current capability
- Low power loss
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

## **APPLICATIONS**

- DC to DC converters
- Switching mode converters and inverters
- Freewheeling application

## **MECHANICAL DATA**

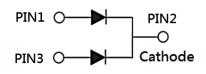
- Case: TO-220AB
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Mounting torque: 0.56 N·m maximum •
- Meet JESD 201 class 2 whisker test
- Polarity: As marked
- Weight: 1.82g (approximately)

KEY PARAMETERS				
PARAMETER	VALUE	UNIT		
I <sub>F</sub>	10	А		
V <sub>RRM</sub>	50 - 600	V		
I <sub>FSM</sub>	125	А		
T <sub>J MAX</sub>	150	°C		
Package	TO-220AB			
Configuration	Dual d	lies		

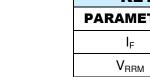








ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25°C unless otherwise noted)										
PARAMETER	SYMBOL	SF 1001G	SF 1002G	SF 1003G	SF 1004G	SF 1005G	SF 1006G	SF 1007G	SF 1008G	UNIT
Marking code on the device		SF 1001G	SF 1002G	SF 1003G	SF 1004G	SF 1005G	SF 1006G	SF 1007G	SF 1008G	
Repetitive peak reverse voltage	V <sub>RRM</sub>	50	100	150	200	300	400	500	600	V
Reverse voltage, total rms value	$V_{R(RMS)}$	35	70	105	140	210	280	350	420	V
Forward current	I <sub>F</sub>		10				А			
Surge peak forward current, 8.3ms single half sine wave superimposed on rated load	I <sub>FSM</sub>	125				A				
Junction temperature	TJ	-55 to +150			°C					
Storage temperature	T <sub>STG</sub>	-55 to +150			°C					







THERMAL PERFORMANCE				
PARAMETER	SYMBOL	ТҮР	UNIT	
Junction-to-case thermal resistance	R <sub>eJC</sub>	3.5	°C/W	

ELECTRICAL SPECIFICATIONS (T <sub>A</sub> = 25°C unless otherwise noted)						
PARAMETER		CONDITIONS	SYMBOL	ТҮР	MAX	UNIT
Forward valtage per diade <sup>(1)</sup>	SF1001G SF1002G SF1003G SF1004G	I <sub>F</sub> = 5A, T <sub>J</sub> = 25°C	V <sub>F</sub>	-	0.975	V
Forward voltage per diode <sup>(1)</sup>	SF1005G SF1006G			-	1.300	V
	SF1007G SF1008G			-	1.700	V
Reverse current @ rated $V_R$ per diode <sup>(2)</sup>		$T_J = 25^{\circ}C$	1	-	10	μA
		T <sub>J</sub> = 100°C	I <sub>R</sub>	-	400	μA
SF1001G SF1002G SF1003G SF1004G			C	70	-	pF
Junction capacitance per diode	SF1005G SF1006G SF1007G SF1008G	1MHz, V <sub>R</sub> = 4.0V	CJ	50	-	pF
Reverse recovery time		$I_F = 0.5A, I_R = 1.0A, I_{rr} = 0.25A$	t <sub>rr</sub>	-	35	ns

#### Notes:

1. Pulse test with PW = 0.3ms

2. Pulse test with PW = 30ms

ORDERING INFORMATION			
ORDERING CODE <sup>(1)(2)</sup>	PACKAGE	PACKING	
SF10xG	TO-220AB	50 / Tube	
SF10xGH	TO-220AB	50 / Tube	

Notes:

1. "x" defines voltage from 50V(SF1001G) to 600V(SF1008G)

2. "H" means AEC-Q101 qualified



100

10

1

0.1

10

20 30

INSTANTANEOUS REVERSE CURRENT (µA)

## **CHARACTERISTICS CURVES**

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 

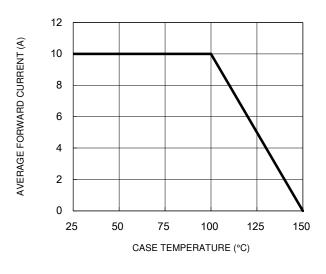
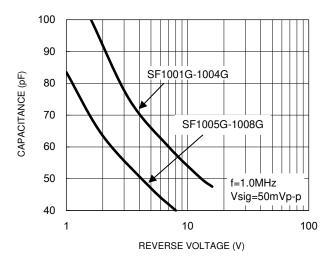


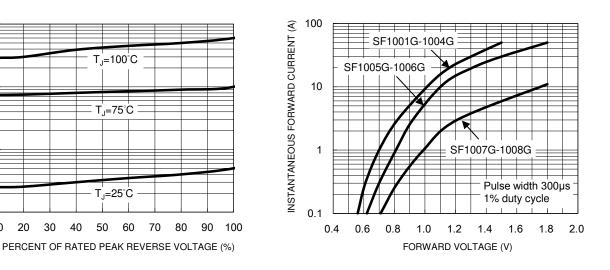
Fig.1 Forward Current Derating Curve

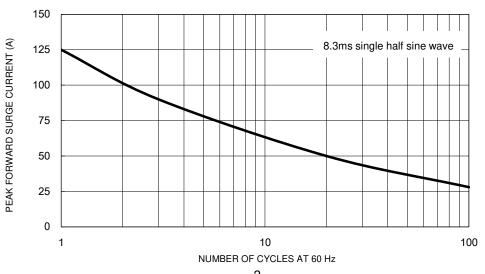
#### **Fig.3 Typical Reverse Characteristics**



#### **Fig.2 Typical Junction Capacitance**

**Fig.4 Typical Forward Characteristics** 





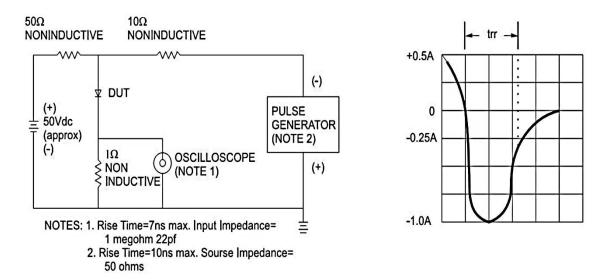
#### Fig.5 Maximum Non-Repetitive Forward Surge Current

Version: K2104



## **CHARACTERISTICS CURVES**

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 

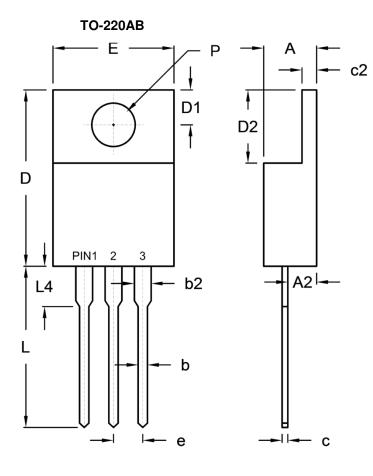


#### Fig.6 Reverse Recovery Time Characteristic and Test Circuit Diagram



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## **PACKAGE OUTLINE DIMENSIONS**



DIM.	Unit (mm)		Unit (	(inch)	
	Min.	Max.	Min.	Max.	
A	4.42	4.76	0.174	0.187	
A2	2.20	2.80	0.087	0.110	
b	0.68	0.94	0.027	0.037	
b2	1.14	1.77	0.045	0.070	
с	0.35	0.64	0.014	0.025	
c2	1.14	1.40	0.045	0.055	
D	14.60	16.00	0.575	0.630	
D1	2.62	3.44	0.103	0.135	
D2	5.84	6.86	0.230	0.270	
E	-	10.50	-	0.413	
е	2.41	2.67	0.095	0.105	
L	13.19	14.79	0.519	0.582	
L4	2.80	4.20	0.110	0.165	
Р	3.54	4.00	0.139	0.157	

#### **MARKING DIAGRAM**



P/N	= Marking Code
G	= Green Compound
YWW	= Date Code
F	= Factory Code



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